

300MHz to 7GHz RF Power Detector with Buffered Output in SC70 Package

FEATURES

- Temperature Compensated Internal Schottky Diode RF Detector
- Wide Input Frequency Range: 300MHz to 7GHz
- Wide Input Power Range: -32dBm to 12dBm
- Buffered Detector Output
- Wide V_{CC} Range of 2.7V to 6V
- Low Operating Current: 550 μ A
- Low Shutdown Current: <2 μ A
- SC70 Package

APPLICATIONS


- 802.11a, 802.11b, 802.11g, 802.15
- Multimode Mobile Phone Products
- Optical Data Links
- Wireless Data Modems
- Wireless and Cable Infrastructure
- RF Power Alarm
- Envelope Detector

DESCRIPTION

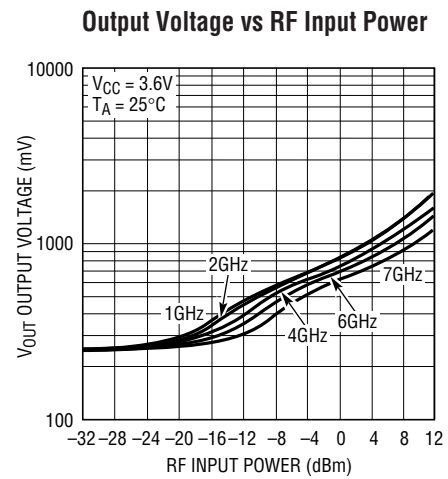
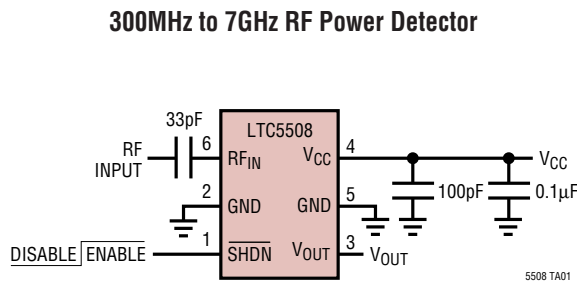
The LTC[®]5508 is an RF power detector for RF applications operating in the 300MHz to 7GHz range. A temperature compensated Schottky diode peak detector and buffer amplifier are combined in a small SC70 package. The supply voltage range is optimized for operation from a single lithium-ion cell or 3xNiMH.

The RF input voltage is peak detected using an on-chip Schottky diode. The detected voltage is buffered and supplied to the V_{OUT} pin. A power saving shutdown mode reduces supply current to less than 2 μ A.

The LTC5508 operates with input power levels from -32dBm to 12dBm.

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TYPICAL APPLICATION

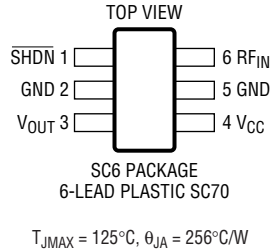


ABSOLUTE MAXIMUM RATINGS

(Note 1)

V_{CC} , V_{OUT} to GND	-0.3V to 6.5V
RF_{IN} Voltage	($V_{CC} \pm 1.3V$) to 7V
SHDN Voltage to GND	-0.3V to ($V_{CC} + 0.3V$)
I_{VOUT}	5mA
Operating Temperature Range (Note 2) ..	-40°C to 85°C
Maximum Junction Temperature	125°C
Storage Temperature Range	-65°C to 150°C
Lead Temperature (Soldering, 10 sec).....	300°C

PACKAGE/ORDER INFORMATION

	ORDER PART NUMBER
	LTC5508ESC6
	SC6 PART MARKING
	LAAD

Consult LTC Marketing for parts specified with wider operating temperature ranges.

ELECTRICAL CHARACTERISTICS

The ● denotes the specifications which apply over the full operating temperature range, otherwise specifications are at $T_A = 25^\circ\text{C}$. $V_{CC} = 3.6V$, $\overline{\text{SHDN}} = V_{CC} = \text{HI}$, $\overline{\text{SHDN}} = 0V = \text{LO}$, RF Input Signal is Off, unless otherwise noted.

PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
V_{CC} Operating Voltage		● 2.7		6	V
I_{VCC} Shutdown Current	$\overline{\text{SHDN}} = \text{LO}$	●		2	μA
I_{VCC} Operating Current	$\overline{\text{SHDN}} = \text{HI}$, $I_{VOUT} = 0\text{mA}$	●	0.55	0.85	mA
V_{OUT} V_{OL} (No RF Input)	$R_{LOAD} = 2k$, $\overline{\text{SHDN}} = \text{HI}$, Enabled $\overline{\text{SHDN}} = \text{LOW}$, Disabled	150	250 1	400	mV mV
V_{OUT} Output Current	$V_{OUT} = 1.75V$, $V_{CC} = 2.7V$, $\Delta V_{OUT} = 10\text{mV}$	● 1	2		mA
V_{OUT} Enable Time	$\overline{\text{SHDN}} = \text{HI}$, $C_{LOAD} = 33\text{pF}$, $R_{LOAD} = 2k$	●	8	20	μs
V_{OUT} Bandwidth	$C_{LOAD} = 33\text{pF}$, $R_{LOAD} = 2k$ (Note 4)		2		MHz
V_{OUT} Load Capacitance	(Note 6)	●		33	pF
V_{OUT} Slew Rate	$V_{RFIN} = 2V$ Step, $C_{LOAD} = 33\text{pF}$, $R_{LOAD} = 2k$ (Note 3)		5		V/ μs
V_{OUT} Noise	$V_{CC} = 3V$, Noise BW = 1.5MHz, 50 Ω RF Input Termination		2		mV _{P-P}
$\overline{\text{SHDN}}$ Voltage, Chip Disabled	$V_{CC} = 2.7V$ to 6V	●		0.35	V
$\overline{\text{SHDN}}$ Voltage, Chip Enabled	$V_{CC} = 2.7V$ to 6V	●	1.4		V
$\overline{\text{SHDN}}$ Input Current	$\overline{\text{SHDN}} = 3.6V$	●	24	40	μA
RF_{IN} Input Frequency Range			300 to 7000		MHz
RF_{IN} Input Power Range	RF Frequency = 300MHz to 7GHz (Note 5, 6) $V_{CC} = 2.7V$ to 6V		-32 to 12		dBm
RF_{IN} AC Input Resistance	$F = 1000\text{MHz}$, $P_{in} = -25\text{dBm}$		150		Ω
RF_{IN} Input Shunt Capacitance	$F = 1000\text{MHz}$, $P_{in} = -25\text{dBm}$		0.6		pF

Note 1: Absolute Maximum Ratings are those values beyond which the life of a device may be impaired.

Note 2: Specifications over the -40°C to 85°C operating temperature range are assured by design, characterization and correlation with statistical process controls.

Note 3: The rise time at V_{OUT} is measured between 0.5V and 1.5V.

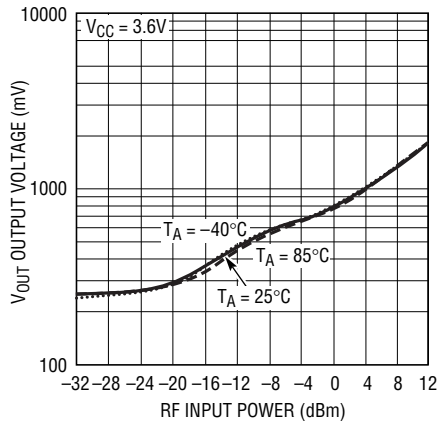
Note 4: Bandwidth is calculated using the 10% to 90% rise time equation: $BW = 0.35/\text{rise time}$.

Note 5: RF performance is tested at 1800MHz

Note 6: Guaranteed by design.

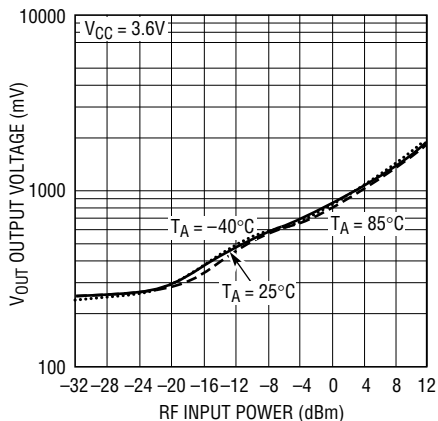
TYPICAL PERFORMANCE CHARACTERISTICS

Typical Detector Characteristics, 300MHz



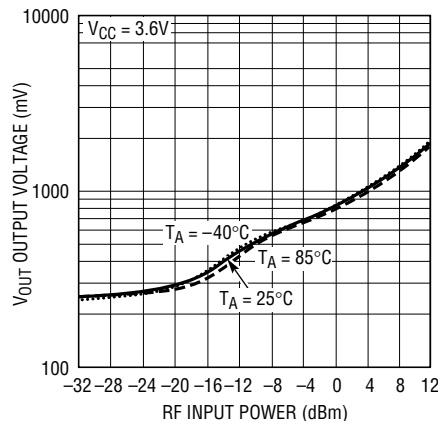
5508 G01

Typical Detector Characteristics, 1000MHz



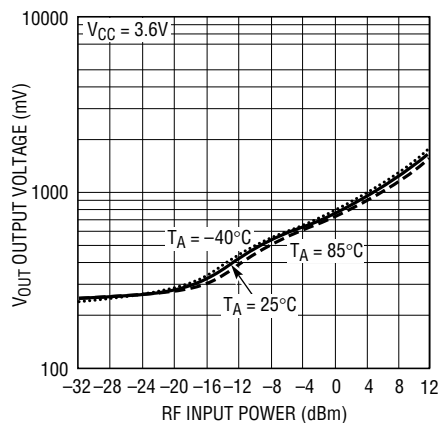
5508 G02

Typical Detector Characteristics, 2000MHz



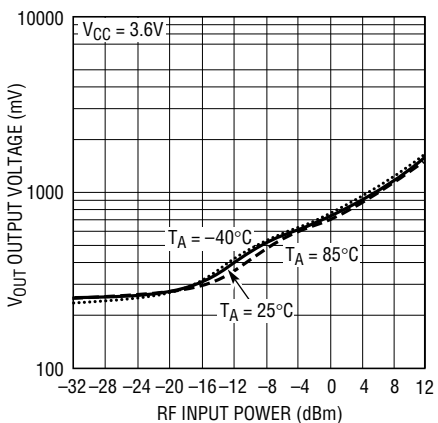
5508 G03

Typical Detector Characteristics, 3000MHz



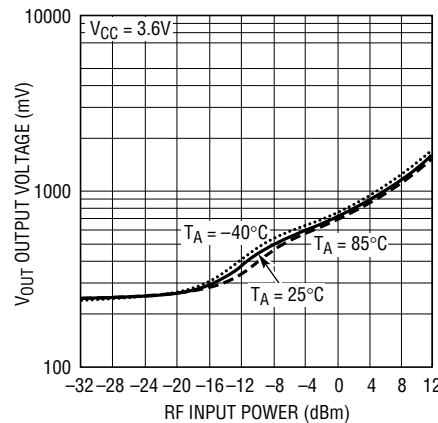
5508 G04

Typical Detector Characteristics, 4000MHz



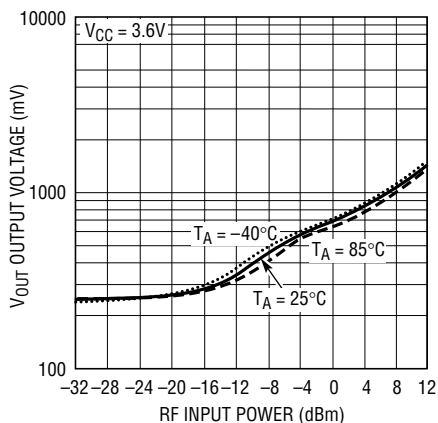
5508 G05

Typical Detector Characteristics, 5000MHz



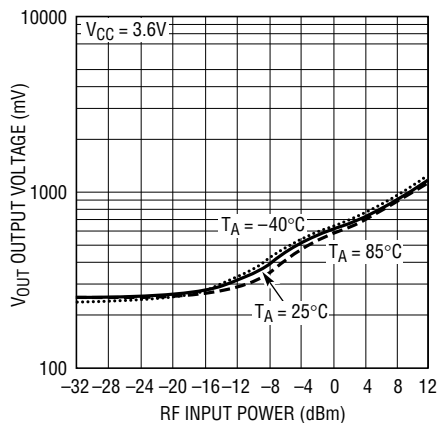
5508 G06

Typical Detector Characteristics, 6000MHz



5508 G07

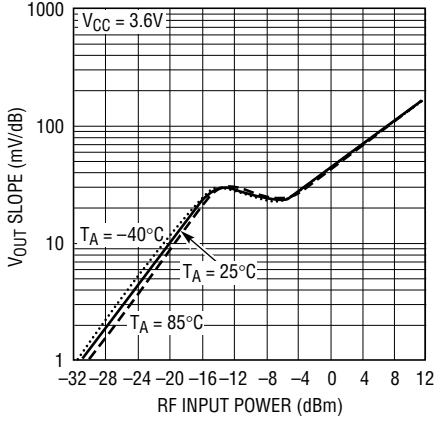
Typical Detector Characteristics, 7000MHz



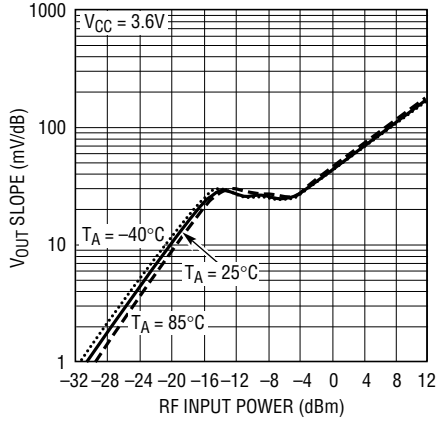
5508 G08

TYPICAL PERFORMANCE CHARACTERISTICS

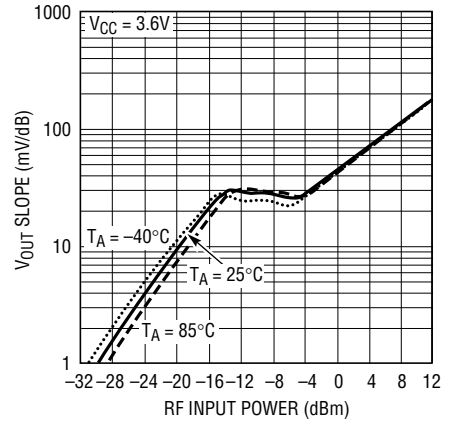
V_{OUT} Slope vs RF Input Power at 300MHz



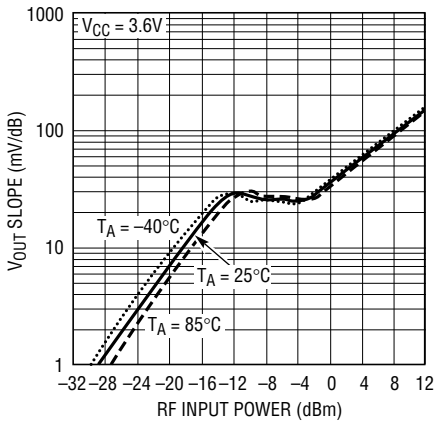
V_{OUT} Slope vs RF Input Power at 1000MHz



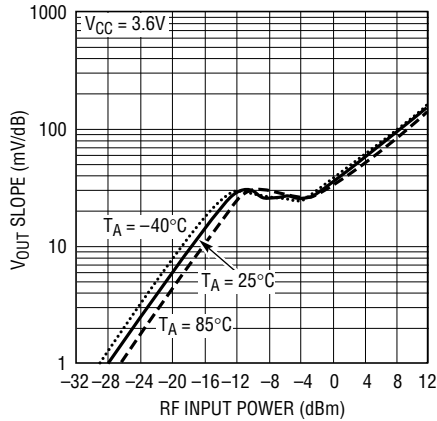
V_{OUT} Slope vs RF Input Power at 2000MHz



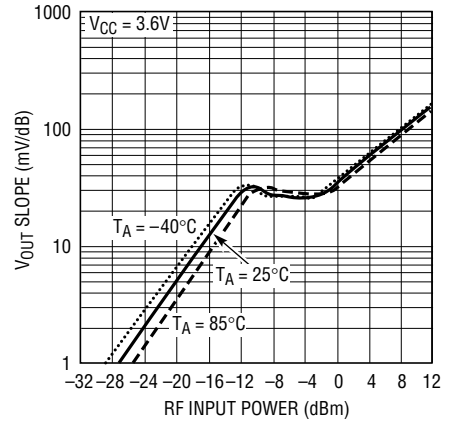
V_{OUT} Slope vs RF Input Power at 3000MHz



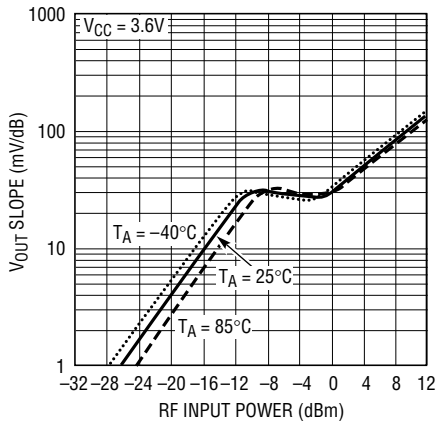
V_{OUT} Slope vs RF Input Power at 4000MHz



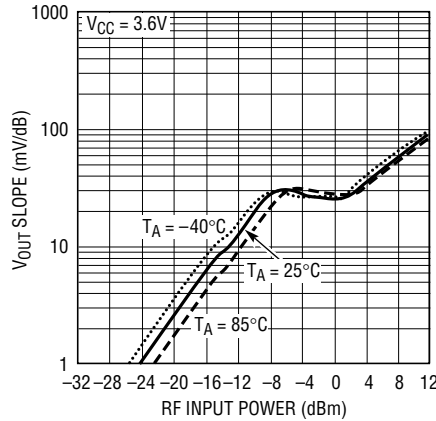
V_{OUT} Slope vs RF Input Power at 5000MHz



V_{OUT} Slope vs RF Input Power at 6000MHz



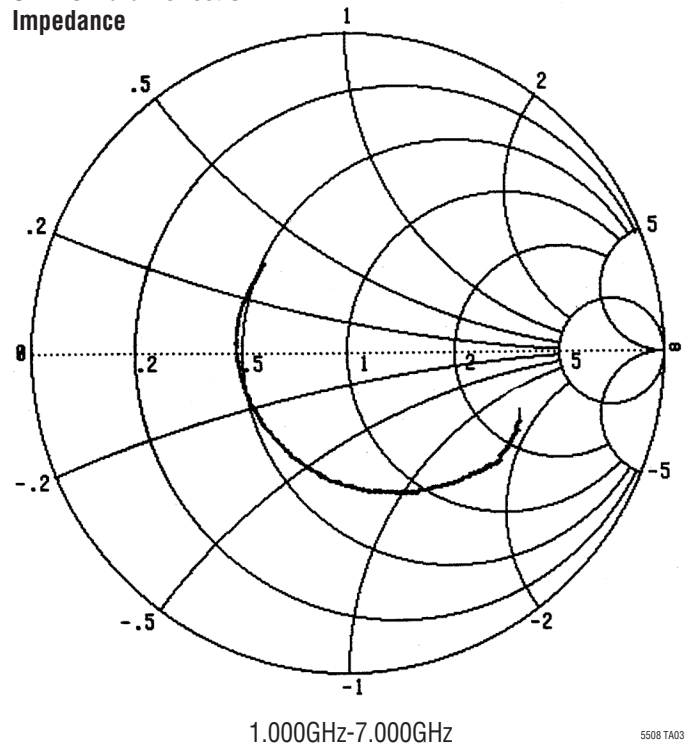
V_{OUT} Slope vs RF Input Power at 7000MHz



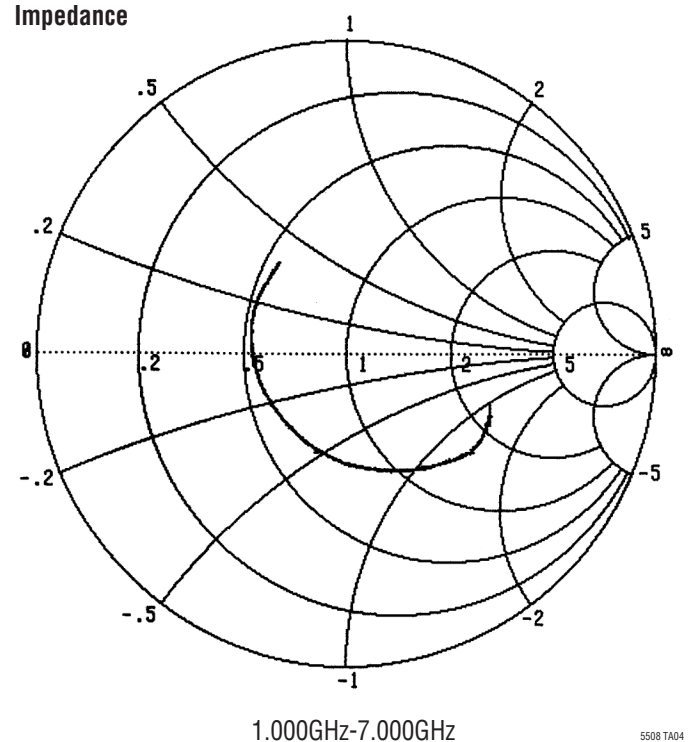
TYPICAL PERFORMANCE CHARACTERISTICS

RF_{IN} Input Impedance (P_{in} = 0dBm, V_{CC} = 3.6V, T_A = 25°C)

FREQUENCY (GHz)	RESISTANCE (Ω)	REACTANCE (Ω)
1.000	129.136	-86.960
1.375	100.771	-92.142
1.750	73.844	-81.141
2.125	60.159	-68.796
2.500	50.135	-58.139
2.875	43.042	-48.927
3.250	37.570	-41.033
3.625	33.924	-33.346
4.000	30.923	-26.405
4.375	28.793	-20.012
4.750	26.992	-14.080
5.125	25.717	-8.323
5.500	24.920	-3.228
5.875	24.318	2.177
6.250	24.549	7.535
6.625	25.273	12.197
7.000	26.337	16.503

S11 Forward Reflection Impedance

RF_{IN} Input Impedance (P_{in} = -25dBm, V_{CC} = 3.6V, T_A = 25°C)

FREQUENCY (GHz)	RESISTANCE (Ω)	REACTANCE (Ω)
1.000	114.531	-63.267
1.375	95.061	-71.669
1.750	71.491	-64.607
2.125	59.563	-54.798
2.500	51.714	-46.844
2.875	44.940	-39.753
3.250	39.708	-32.738
3.625	36.151	-26.385
4.000	33.227	-20.478
4.375	31.108	-15.107
4.750	29.514	-9.941
5.125	27.899	-4.793
5.500	27.047	0.266
5.875	26.627	5.250
6.250	26.760	10.267
6.625	27.619	14.616
7.000	28.241	18.523

S11 Forward Reflection Impedance


PIN FUNCTIONS

SHDN (Pin 1): Shutdown Input. A logic low on the SHDN pin places the part in shutdown mode. A logic high enables the part. SHDN has an internal 150k pull down resistor to ensure that the part is in shutdown when no input is applied.

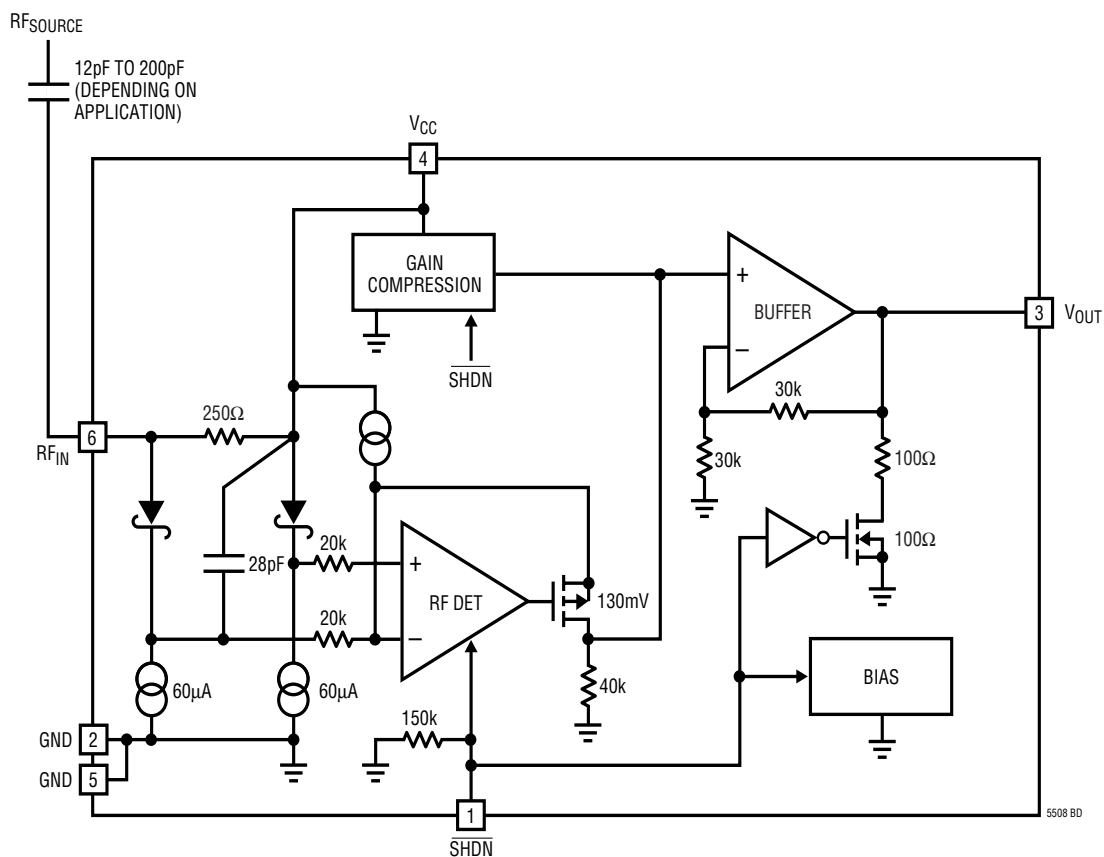
GND (Pin 2, 5): Ground.

V_{OUT} (Pin 3): Detector Output.

V_{CC} (Pin 4): Power Supply Voltage, 2.7V to 6V. V_{CC} should be bypassed appropriately with ceramic capacitors.

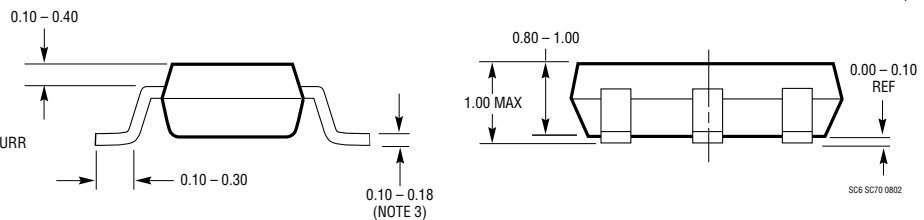
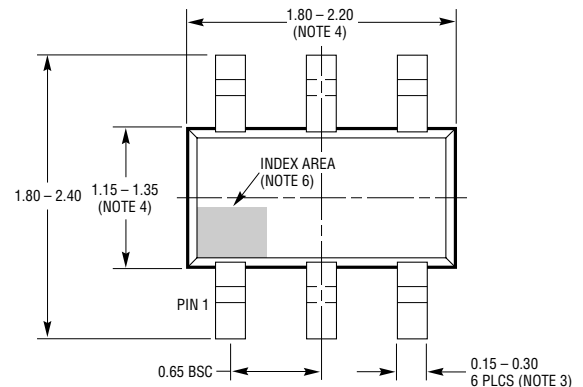
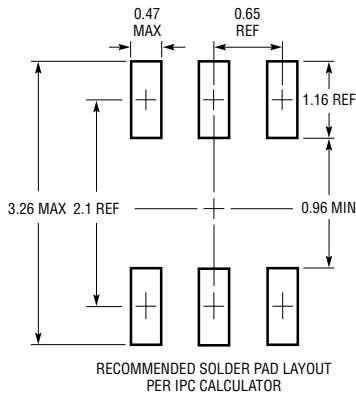
RF_{IN} (Pin 6): RF Input Voltage. Referenced to V_{CC}. A coupling capacitor must be used to connect to the RF signal source. The frequency range is 300MHz to 7GHz. This pin has an internal 250Ω termination, an internal Schottky diode detector and a peak detector capacitor.

BLOCK DIAGRAM



PACKAGE DESCRIPTION

SC6 Package
6-Lead Plastic SC70
 (Reference LTC DWG # 05-08-1638)



- NOTE:
1. DIMENSIONS ARE IN MILLIMETERS
 2. DRAWING NOT TO SCALE
 3. DIMENSIONS ARE INCLUSIVE OF PLATING
 4. DIMENSIONS ARE EXCLUSIVE OF MOLD FLASH AND METAL BURR
 5. MOLD FLASH SHALL NOT EXCEED 0.254mm
 6. DETAILS OF THE PIN 1 IDENTIFIER ARE OPTIONAL, BUT MUST BE LOCATED WITHIN THE INDEX AREA
 7. EIAJ PACKAGE REFERENCE IS EIAJ SC-70

RELATED PARTS

PART NUMBER	DESCRIPTION	COMMENTS
RF Power Controllers		
LTC1757A	RF Power Controller	Single/Dual Band GSM/DCS/GPRS Mobile Phones
LTC1758	RF Power Controller	Single/Dual Band GSM/DCS/GPRS Mobile Phones
LTC1957	RF Power Controller	Single/Dual Band GSM/DCS/GPRS Mobile Phones
LTC4400	SOT-23 RF PA Controller	Single/Dual Band GSM/DCS/GPRS Phones, 45dB Dynamic Range, 450kHz Loop BW
LTC4401	SOT-23 RF PA Controller	Single/Dual Band GSM/DCS/GPRS Phones, 45dB Dynamic Range, 250kHz Loop BW
LT5500	1.8GHz to 2.7GHz RF Front End	Dual LNA gain Setting +13.5dB/-14dB at 2.5GHz, Double-Balanced Mixer, $1.8V \leq V_{SUPPLY} \leq 5.25V$
LT5502	400MHz Quadrature Demodulator with RSSI	1.8V to 5.25V Supply, 70MHz to 400MHz IF, 84dB Limiting Gain, 90dB RSSI Range
LT5503	1.2GHz to 2.7GHz Direct IQ Modulator and Up Converting Mixer	1.8V to 5.25V Supply, Four-Step RF Power Control, 120MHz Modulation Bandwidth
LT5504	800MHz to 2.7GHz RF Measuring Receiver	80dB Dynamic Range, Temperature Compensated, 2.7V to 5.5V Supply
LTC5505	300MHz to 3.5GHz RF Power Detector	>40dB Dynamic Range, Temperature Compensated, 2.7V to 6V Supply
LT5506	500MHz Quadrature IF Demodulator with VGA	1.8V to 5.25V Supply, 40MHz to 500MHz IF, -4dB to 57dB Linear Power Gain
LTC5507	100kHz to 1GHz RF Power Detector	48dB Dynamic Range, Temperature Compensated, 2.7V to 6V Supply
LT5511	High Signal Level Up Converting Mixer	RF Output to 3GHz, 17dBm IIP3, Integrated LO Buffer
LT5512	High Signal Level Down Converting Mixer	DC-3GHz, 20dBm IIP3, Integrated LO Buffer

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